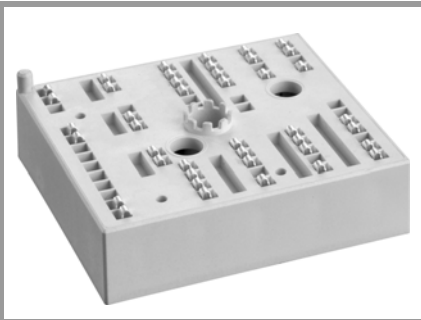


# SKiiP 26AC12T4V1



MiniSKiiP® 2

## SKiiP 26AC12T4V1

### Features

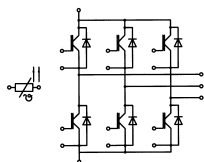
- Trench 4 IGBT's
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

### Typical Applications\*

- Inverter up to 29 kVA
- Typical motor power 18,5 kW

### Remarks

- $V_{CEsat}$ ,  $V_F$  = chip level value
- Case temp. limited to  $T_C = 125^\circ\text{C}$  max. (for baseplateless modules  $T_C = T_S$ )
- product rel. results valid for  $T_j \leq 150$  (recomm.  $T_{op} = -40 \dots +150^\circ\text{C}$ )



AC

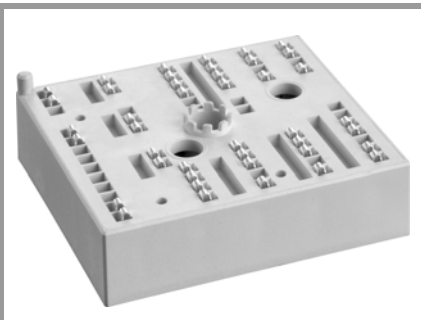
### Absolute Maximum Ratings

Symbol	Conditions	Values	Unit	
<b>Inverter - IGBT</b>				
$V_{CES}$	$T_j = 25^\circ\text{C}$	1200	V	
$I_C$	$T_j = 175^\circ\text{C}$	$T_s = 25^\circ\text{C}$	90	A
		$T_s = 70^\circ\text{C}$	73	A
$I_{Cnom}$		70	A	
$I_{CRM}$	$I_{CRM} = 3 \times I_{Cnom}$	210	A	
$V_{GES}$		-20 ... 20	V	
$t_{psc}$	$V_{CC} = 800\text{ V}$ $V_{GE} \leq 15\text{ V}$ $V_{CES} \leq 1200\text{ V}$	$T_j = 150^\circ\text{C}$	10	$\mu\text{s}$
$T_j$		-40 ... 175	$^\circ\text{C}$	
<b>Inverse - Diode</b>				
$I_F$	$T_j = 175^\circ\text{C}$	$T_s = 25^\circ\text{C}$	83	A
		$T_s = 70^\circ\text{C}$	66	A
$I_{Fnom}$		75	A	
$I_{FRM}$	$I_{FRM} = 3 \times I_{Fnom}$	225	A	
$I_{FSM}$	10 ms, sin 180°, $T_j = 150^\circ\text{C}$	430	A	
$T_j$		-40 ... 175	$^\circ\text{C}$	
<b>Module</b>				
$I_{t(RMS)}$	$T_{terminal} = 80^\circ\text{C}$ , 20A per spring	100	A	
$T_{stg}$		-40 ... 125	$^\circ\text{C}$	
$V_{isol}$	AC sinus 50Hz, t = 1 min	2500	V	

### Characteristics

Symbol	Conditions	min.	typ.	max.	Unit
<b>Inverter - IGBT</b>					
$V_{CE(sat)}$	$I_C = 70\text{ A}$ $V_{GE} = 15\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$	1.85	2.10	V
		$T_j = 150^\circ\text{C}$	2.25	2.45	V
$V_{CE0}$		$T_j = 25^\circ\text{C}$	0.8	0.9	V
		$T_j = 150^\circ\text{C}$	0.7	0.8	V
$r_{CE}$	$V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$	15	17	m $\Omega$
		$T_j = 150^\circ\text{C}$	22	24	m $\Omega$
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 2\text{ mA}$	5	5.8	6.5	V
$I_{CES}$	$V_{GE} = 0\text{ V}$ $V_{CE} = 1200\text{ V}$	$T_j = 25^\circ\text{C}$	0.1	0.3	mA
					mA
$C_{ies}$	$V_{CE} = 25\text{ V}$		3.90		nF
$C_{oes}$	$V_{GE} = 0\text{ V}$		0.31		nF
$C_{res}$			0.23		nF
$Q_G$	- 8 V...+ 15 V		400		nC
$R_{Gint}$	$T_j = 25^\circ\text{C}$		0.00		$\Omega$
$t_{d(on)}$	$V_{CC} = 600\text{ V}$	$T_j = 150^\circ\text{C}$	26		ns
$t_r$	$I_C = 75\text{ A}$	$T_j = 150^\circ\text{C}$	36		ns
$E_{on}$	$R_{Gon} = 9.1\ \Omega$ $R_{Goff} = 9.1\ \Omega$	$T_j = 150^\circ\text{C}$	9.5		mJ
$t_{d(off)}$	$di/dt_{on} = 1820\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	320		ns
$t_f$	$di/dt_{off} = 900\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	175		ns
$E_{off}$	$V_{GE} = +15/-15\text{ V}$	$T_j = 150^\circ\text{C}$	7.1		mJ
$R_{th(j-s)}$	per IGBT		0.55		K/W

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MiniSKiiP® 2

## SKiiP 26AC12T4V1

### Features

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- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

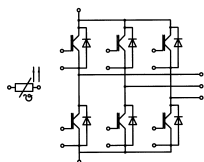
### Typical Applications\*

- Inverter up to 29 kVA
- Typical motor power 18,5 kW

### Remarks

- $V_{CEsat}$ ,  $V_F$ = chip level value
- Case temp. limited to  $T_C = 125^\circ\text{C}$  max. (for baseplateless modules  $T_C = T_S$ )
- product rel. results valid for  $T_j \leq 150$  (recomm.  $T_{op} = -40 \dots +150^\circ\text{C}$ )

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
<b>Inverse - Diode</b>						
$V_F = V_{EC}$	$I_F = 75 \text{ A}$ $V_{GE} = 0 \text{ V}$ chiplevel	$T_j = 25^\circ\text{C}$		2.2	2.5	V
		$T_j = 150^\circ\text{C}$		2.1	2.4	V
$V_{F0}$		$T_j = 25^\circ\text{C}$		1.3	1.5	V
		$T_j = 150^\circ\text{C}$		0.9	1.1	V
$r_F$		$T_j = 25^\circ\text{C}$		12	13	m $\Omega$
		$T_j = 150^\circ\text{C}$		16	18	m $\Omega$
$I_{RRM}$	$I_F = 75 \text{ A}$	$T_j = 150^\circ\text{C}$		80		A
$Q_{rr}$	$di/dt_{off} = 2120 \text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$		13.3		$\mu\text{C}$
$E_{rr}$	$V_{GE} = -15 \text{ V}$ $V_{CC} = 600 \text{ V}$	$T_j = 150^\circ\text{C}$		5.6		mJ
$R_{th(j-s)}$	per Diode			0.75		K/W
<b>Module</b>						
$M_s$	to heat sink		2		2.5	Nm
w				65		g
<b>Temperatur Sensor</b>						
$R_{100}$	$T_C = 100^\circ\text{C}$ ( $R_{25} = 1000\Omega$ )			1670 $\pm$ 3%		$\Omega$
$R(T)$	$R(T) = 1000\Omega [1 + A(T - 25^\circ\text{C}) + B(T - 25^\circ\text{C})^2]$ ], $A = 7.635 \cdot 10^{-3} \text{ }^\circ\text{C}^{-1}$ , $B = 1.731 \cdot 10^{-5} \text{ }^\circ\text{C}^{-2}$					



AC

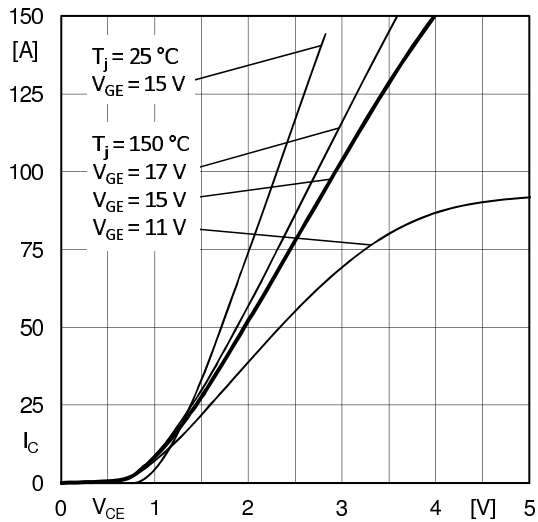


Fig. 1: Typ. output characteristic, inclusive  $R_{CC'+EE'}$

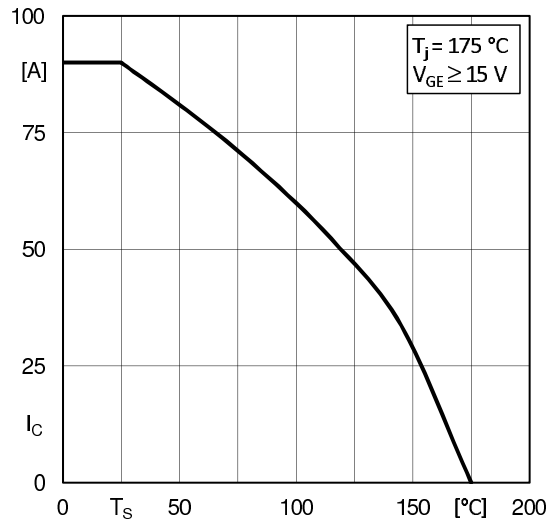


Fig. 2: Rated current vs. temperature  $I_C = f(T_S)$

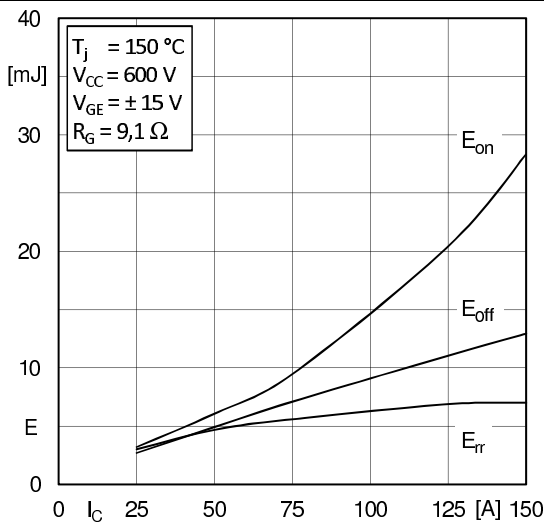


Fig. 3: Typ. turn-on /-off energy =  $f(I_C)$

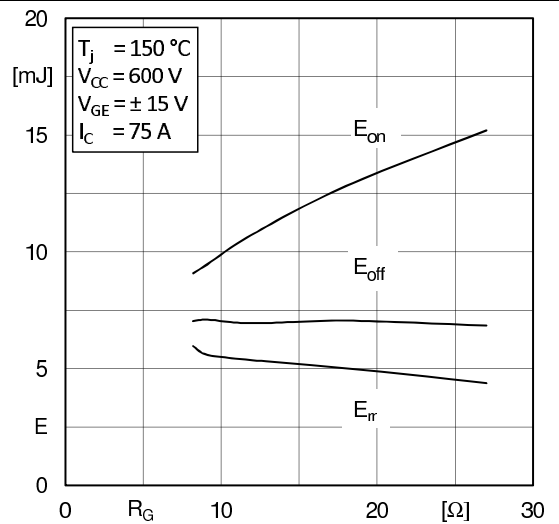


Fig. 4: Typ. turn-on /-off energy =  $f(R_G)$

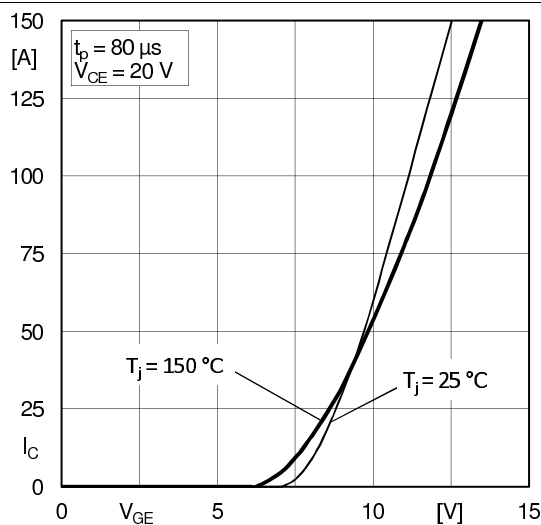


Fig. 5: Typ. transfer characteristic

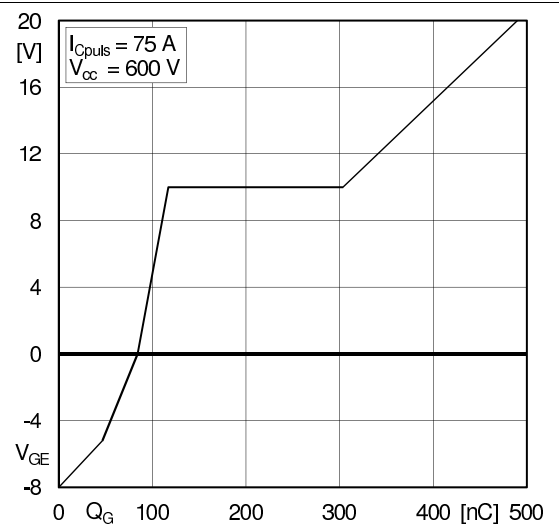


Fig. 6: Typ. gate charge characteristic

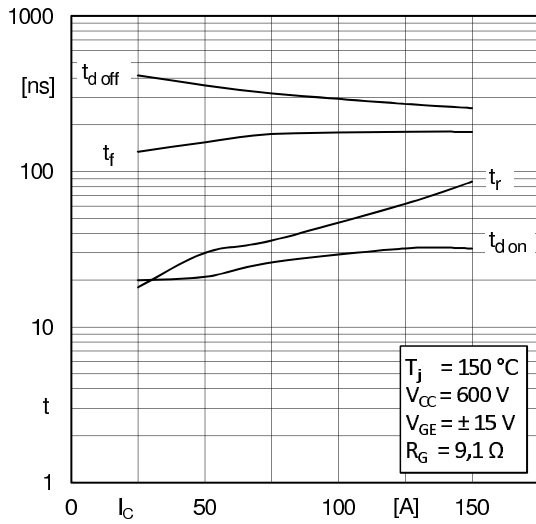


Fig. 7: Typ. switching times vs.  $I_C$

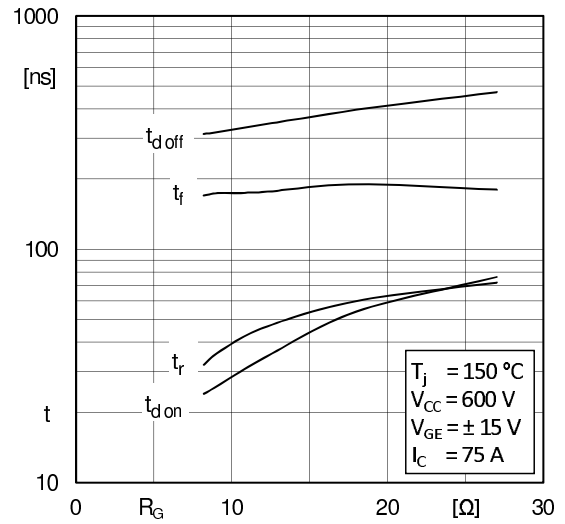


Fig. 8: Typ. switching times vs. gate resistor  $R_G$

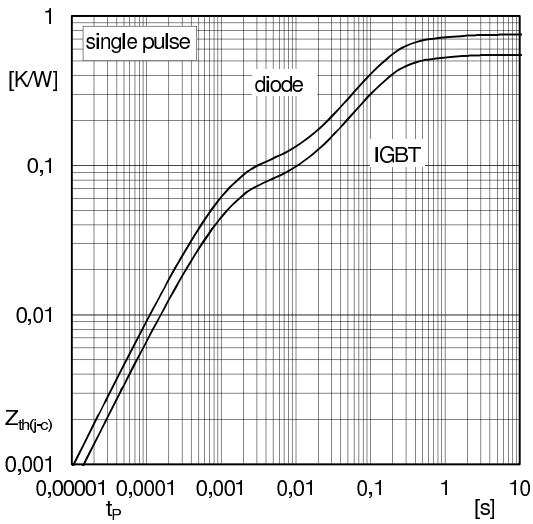


Fig. 9: Transient thermal impedance of IGBT and Diode

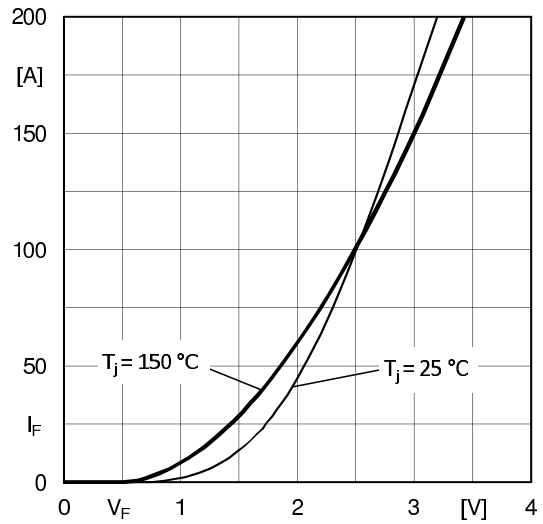


Fig. 10: CAL diode forward characteristic

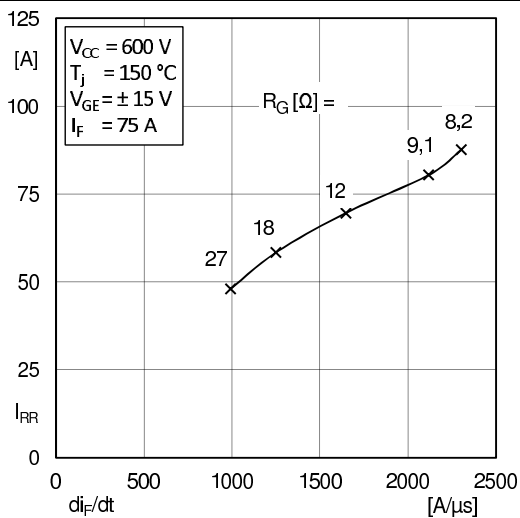


Fig. 11: Typ. CAL diode peak reverse recovery current

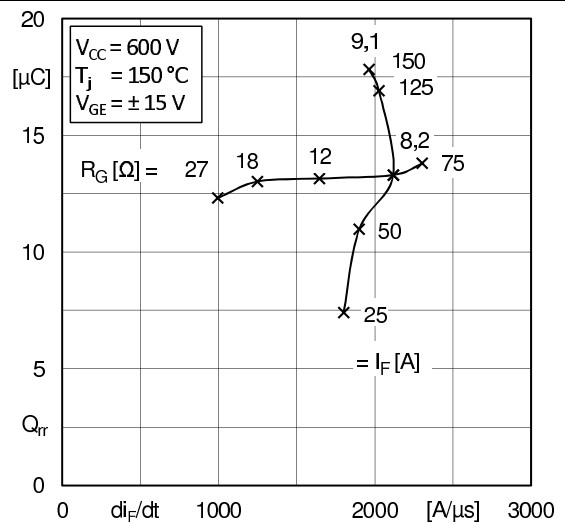
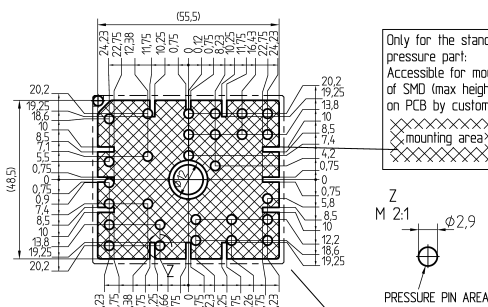


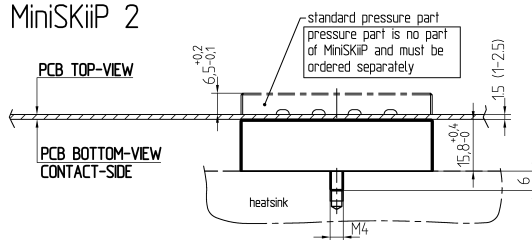
Fig. 12: Typ. CAL diode recovery charge

# SKiIP 26AC12T4V1

PCB TOP-VIEW



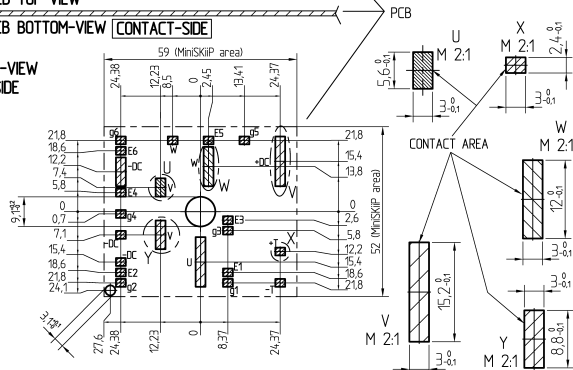
MiniSKiIP 2



PCB TOP-VIEW

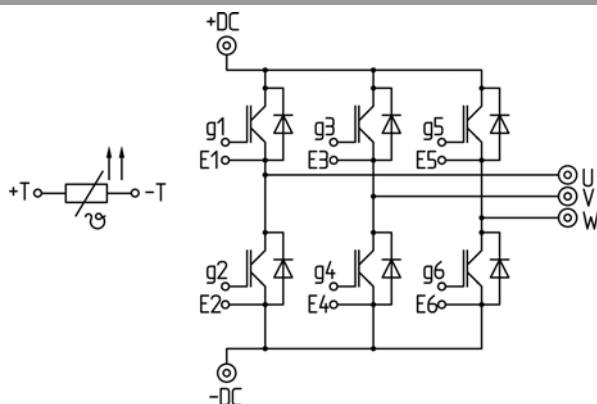
PCB BOTTOM-VIEW CONTACT-SIDE

PCB BOTTOM-VIEW CONTACT-SIDE



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pinout, dimensions



- ⊙ power connector
- control connector

pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

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